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FAIRCHILD

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FDS6612A

Single N-Channel, Logic-Level, PowerTrench® MOSFET

General Description

This N-Channel Logic Level MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

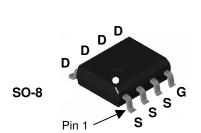
These devices are well suited for low voltage and battery powered applications where low in-line power loss and fast switching are required.

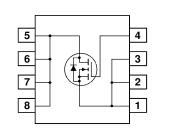


Features

• 8.4 A, 30 V. $R_{DS(ON)} = 22 \ m\Omega @ V_{GS} = 10 \ V$ $R_{DS(ON)} = 30 \ m\Omega @ V_{GS} = 4.5 \ V$

- Fast switching speed
- Low gate charge
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DSS}	Drain-Source Voltage			30	V
V _{GSS}	Gate-Source Voltage		±20	V	
I _D	Drain Curre	nt – Continuous	(Note 1a)	8.4	A
		– Pulsed		40	
PD	Power Diss	ipation for Single Operat	ion (Note 1a)	2.5	W
			(Note 1b)	1.0	
E _{AS}	Single Pulse Avalanche Energy (Note 3)		(Note 3)	24	mJ
Tj, T _{stg}	Operating and Storage Junction Temperature Range		nperature Range	-55 to +150	
	I Charac		·· · ·	50	
R _{θJA}	Thermal Re	rmal Resistance, Junction-to-Ambient (Note 1a) 50		°C/W	
R _{eja}	Thermal Resistance, Junction-to-Ambient (Note 1b)		nbient (Note 1b)	125	
R _{eJC}	Thermal Resistance, Junction-to-Case (Note 1)		25		
Packag	e Markin	g and Ordering	Information		
Device I		Device	Reel Size	Tape width	Quantity
FDS6	0104	FDS6612A	13"	12mm	2500 units

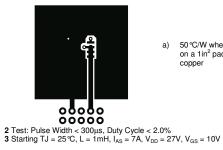
FDS6612A Rev D1 (W)

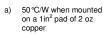
FDS6612A Single N-Channel, Logic-Level, PowerTrench[®] MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	30			V
ΔBV_{DSS} $\Delta T_{.1}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		26		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V$, $V_{GS} = 0 V$			1	μA
		$V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			10	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1	1.9	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-4.4		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{ll} V_{GS} = 10 \ V, & I_D = 8.4 \ A \\ V_{GS} = 4.5 \ V, & I_D = 7.2 \ A \\ V_{GS} = 10 \ V, \ I_D = 8.4 \ A, \ T_J = 125^\circ C \end{array} $		19 24 25	22 30 37	mΩ
I _{D(on)}	On-State Drain Current	$V_{GS} = 10 \text{ V}, \qquad V_{DS} = 5 \text{ V}$	20			Α
g fs	Forward Transconductance	$V_{DS} = 15 V$, $I_D = 8.4 A$		30		S
Dynamic	Characteristics					
Ciss	Input Capacitance	$V_{DS} = 15 V$, $V_{GS} = 0 V$,		560		pF
Coss	Output Capacitance	f = 1.0 MHz		140		pF
C _{rss}	Reverse Transfer Capacitance			55		pF
R _G	Gate Resistance	$V_{\text{GS}} = 15 \text{ mV}, f = 1.0 \text{ MHz}$		2.5		Ω
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 15 V, \qquad I_D = 1 A,$		7	14	ns
tr	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$		5	10	ns
t _{d(off)}	Turn–Off Delay Time			22	35	ns
t _f	Turn-Off Fall Time			3	6	ns
Qg	Total Gate Charge	$V_{DS} = 15 V$, $I_D = 8.4 A$,		5.4	7.6	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = 5 V$		1.7		nC
Q _{gd}	Gate-Drain Charge			1.9		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain-Source	Diode Forward Current			2.1	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \ V,$ $I_{S} = 2.1 \ A \ (Note 2)$		0.77	1.2	V
t _{rr}	Diode Reverse Recovery Time	I _F = 8.4 A, d _{iF} /d _t = 100 A/μs		19		nS
Q _{rr}	Diode Reverse Recovery Charge	$r_F = 0.7 \Lambda, u_{iF}/u_t = 100 \Lambda/\mu S$	1	9		nC

Notes:

1. R_{8JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $\rm R_{6JC}$ is guaranteed by design while $\rm R_{6CA}$ is determined by the user's board design.



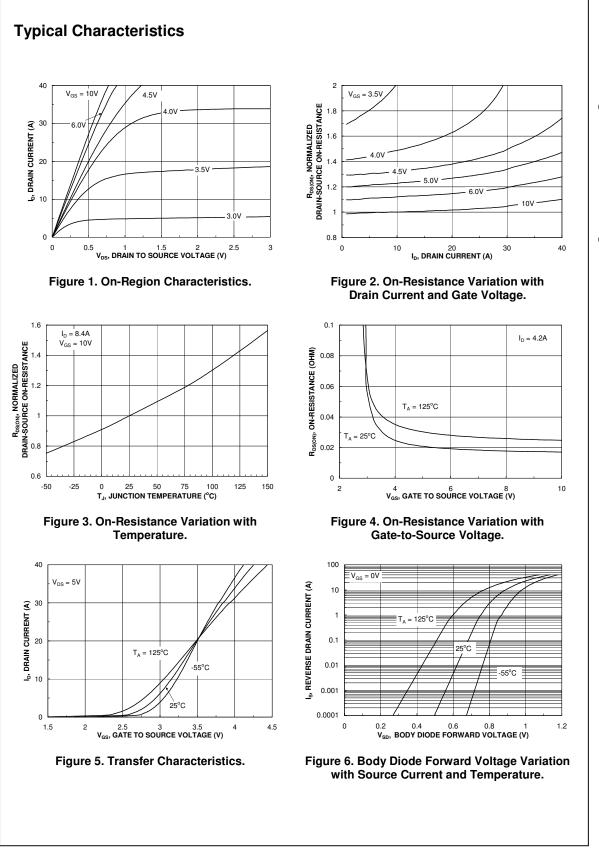




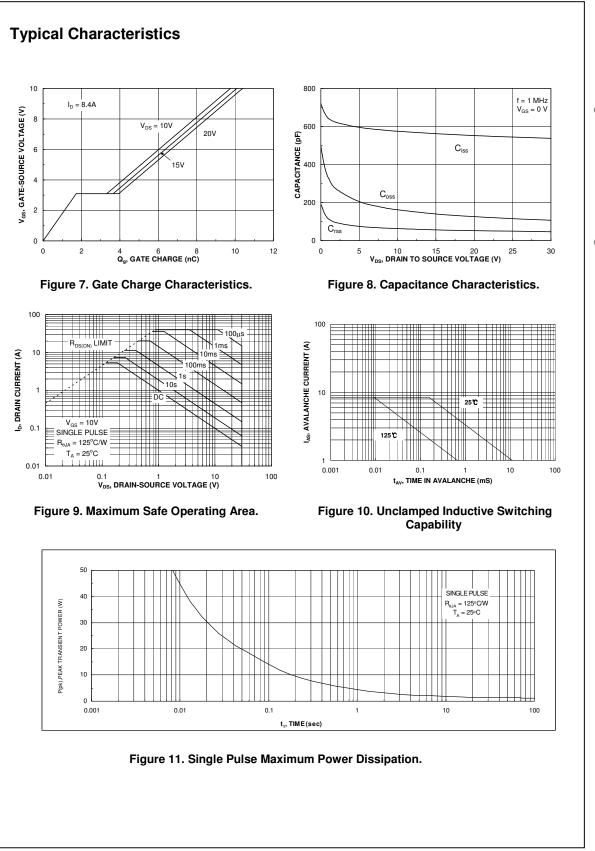
b) 125°C/W when mounted on a minimum pad.

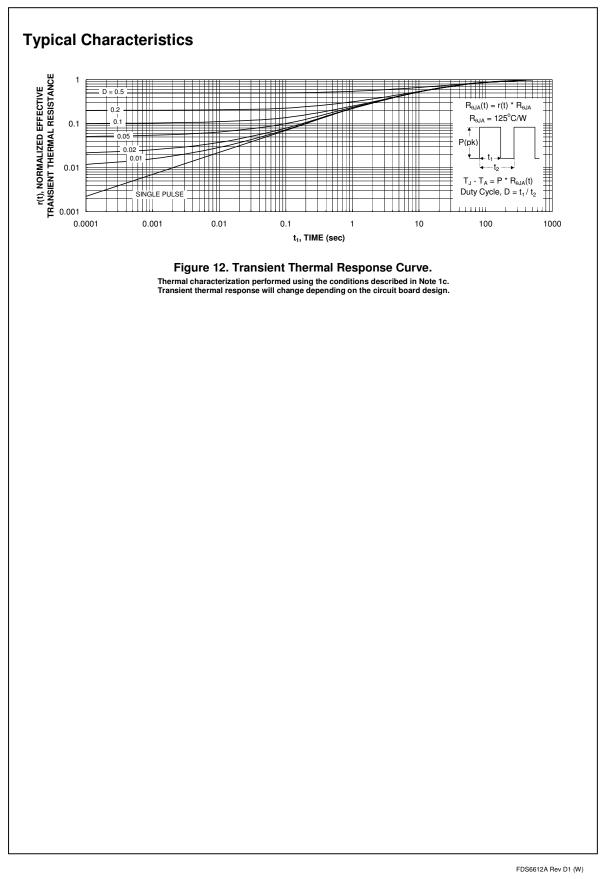
Scale 1 : 1 on letter size paper

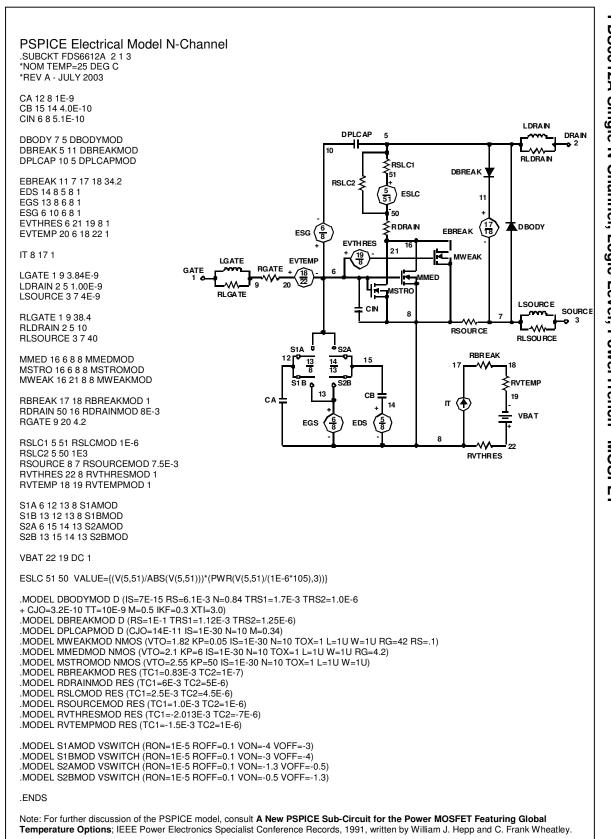
FDS6612A Single N-Channel, Logic-Level, PowerTrench[®] MOSFET



FDS6612A Single N-Channel, Logic-Level, PowerTrench[®] MOSFET





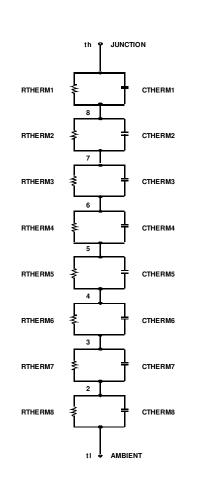


SPICE Thermal Model

.SUBCKT FDS6612A_THERM TH TL *THERMAL MODEL SUBCIRCUIT *REV A - JULY 2003 *MIN PAD RJA

CTHERM1	TH	8	0.005
CTHERM2	8	7	0.05
CTHERM3	7	6	0.10
CTHERM4	6	5	0.35
CTHERM5	5	4	0.45
CTHERM6	4	3	0.50
CTHERM7	3	2	0.55
CTHERM8	2	TL	3.00
RTHERM1	TH	8	5.000
RTHERM2	8	7	6.250
RTHERM3	7	6	7.500
RTHERM4	6	5	8.750
RTHERM5	5	4	10.625
RTHERM6	4	3	11.875
RTHERM7	3	2	31.250
RTHERM8	2	TL	43.750

.ENDS





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